

# SN54ALS640B, SN54AS640, SN74ALS640B, SN74AS640

## OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SDAS122A – DECEMBER 1983 – REVISED JANUARY 1995

- Bidirectional Bus Transceivers in High-Density 20-Pin Packages
- Inverting Logic
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK), and Standard Plastic (N) and Ceramic (J) 300-mil DIPs

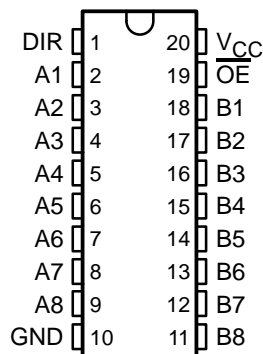
### description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. These devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending upon the level at the direction-control (DIR) input. The output-enable ( $\overline{OE}$ ) input can be used to disable the device so that the buses are effectively isolated.

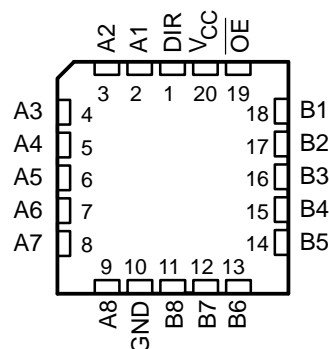
The -1 version of the SN74ALS640B is identical to the standard version, except that the recommended maximum  $I_{OL}$  for the -1 version is increased to 48 mA. There is no -1 version of the SN54ALS640B.

The SN54ALS640B and SN54AS640 are characterized for operation over the full military temperature range of  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ . The SN74ALS640B and SN74AS640 are characterized for operation from  $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$ .

SN54ALS640B, SN54AS640 . . . J PACKAGE  
SN74ALS640B, SN74AS640 . . . DW OR N PACKAGE  
(TOP VIEW)



SN54ALS640B, SN54AS640 . . . FK PACKAGE  
(TOP VIEW)



FUNCTION TABLE

INPUTS		OPERATION
$\overline{OE}$	DIR	
L	L	$\overline{B}$ data to A bus
L	H	$\overline{A}$ data to B bus
H	X	Isolation

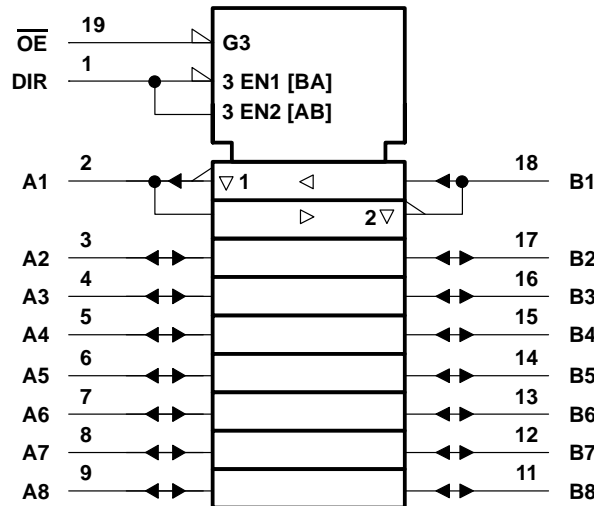
# SN54ALS640B, SN54AS640, SN74ALS640B, SN74AS640

## OCTAL BUS TRANSCEIVERS

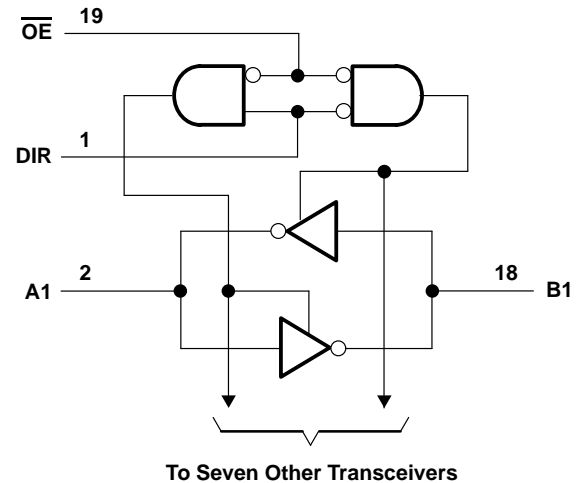
### WITH 3-STATE OUTPUTS

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#### logic symbol†



#### logic diagram (positive logic)



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage, $V_{CC}$	7 V
Input voltage, $V_I$ : All inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, $T_A$ : SN54ALS640B	–55°C to 125°C
SN74ALS640B	0°C to 70°C
Storage temperature range	–65°C to 150°C

‡ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

		SN54ALS640B			SN74ALS640B			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
$V_{CC}$	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
$V_{IH}$	High-level input voltage	2			2			V
$V_{IL}$	Low-level input voltage			0.7			0.8	V
$I_{OH}$	High-level output current			–12			–15	mA
$I_{OL}$	Low-level output current			12			24	mA
							48§	
$T_A$	Operating free-air temperature	–55		125	0		70	°C

§ Applies only to the -1 version and only if  $V_{CC}$  is between 4.75 V and 5.25 V

# SN54ALS640B, SN54AS640, SN74ALS640B, SN74AS640

## OCTAL BUS TRANSCEIVERS

### WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54ALS640B		SN74ALS640B		UNIT
				MIN	TYP†	MAX	MIN	
V <sub>IK</sub>		V <sub>CC</sub> = 4.5 V, I <sub>I</sub> = −18 mA		−1.5		−1.5		V
V <sub>OH</sub>		V <sub>CC</sub> = 4.5 V to 5.5 V, I <sub>OH</sub> = −0.4 mA		V <sub>CC</sub> − 2		V <sub>CC</sub> − 2		V
		V <sub>CC</sub> = 4.5 V	I <sub>OH</sub> = −3 mA	2.4	3.2	2.4	3.2	
			I <sub>OH</sub> = −12 mA	2				
			I <sub>OH</sub> = −15 mA			2		
V <sub>OL</sub>		V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 12 mA	0.25	0.4	0.25	0.4	V
			I <sub>OL</sub> = 24 mA			0.35	0.5	
			I <sub>OL</sub> = 48 mA‡			0.35	0.5	
I <sub>I</sub>	Control inputs	V <sub>CC</sub> = 5.5 V	V <sub>I</sub> = 7 V	0.1		0.1		mA
	A or B ports		V <sub>I</sub> = 5.5 V	0.1		0.1		
I <sub>IH</sub>	Control inputs	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 2.7 V	20		20		μA	
	A or B ports§		20		20			
I <sub>IL</sub>	Control inputs	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0.4 V	−0.1		−0.1		mA	
	A or B ports§		−0.1		−0.1			
I <sub>O</sub> ¶		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 2.25 V	−20	−112	−30	−112	mA	
I <sub>CC</sub>		V <sub>CC</sub> = 5.5 V	Outputs high	19	50	19	45	mA
			Outputs low	27	60	27	55	
			Outputs disabled	28	55	28	50	

† All typical values are at  $V_{CC} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

‡ Applies only to the -1 version and only if  $V_{CC}$  is between 4.75 V and 5.25 V

§ For I/O ports, the parameters  $I_{IH}$  and  $I_{IL}$  include the off-state output current.

¶ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current,  $I_{OS}$ .

### switching characteristics (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 4.5 V to 5.5 V, C <sub>L</sub> = 50 pF, R <sub>1</sub> = 500 Ω, R <sub>2</sub> = 500 Ω, T <sub>A</sub> = MIN to MAX#				UNIT
			SN54ALS640B		SN74ALS640B		
			MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	B or A	2	14	2	11	ns
t <sub>PHL</sub>			2	13	2	10	
t <sub>PZH</sub>	$\overline{OE}$	A or B	4	25	4	21	ns
t <sub>PZL</sub>			5	27	5	24	
t <sub>PHZ</sub>	$\overline{OE}$	A or B	2	12	2	10	ns
t <sub>PLZ</sub>			3	20	3	15	

# For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

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## OCTAL BUS TRANSCEIVERS

### WITH 3-STATE OUTPUTS

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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, $V_{CC}$	7 V
Input voltage, $V_I$ : All inputs	7 V
I/O ports	5.5 V
Operating free-air temperature range, $T_A$ : SN54AS640	–55°C to 125°C
SN74AS640	0°C to 70°C
Storage temperature range	–65°C to 150°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### recommended operating conditions

		SN54AS640			SN74AS640			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
$V_{CC}$	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
$V_{IH}$	High-level input voltage	2			2			V
$V_{IL}$	Low-level input voltage			0.8			0.8	V
$I_{OH}$	High-level output current			–12			–15	mA
$I_{OL}$	Low-level output current			48			64	mA
$T_A$	Operating free-air temperature	–55		125	0		70	°C

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54AS640			SN74AS640			UNIT	
				MIN	TYP‡	MAX	MIN	TYP‡	MAX		
V <sub>IK</sub>		V <sub>CC</sub> = 4.5 V, I <sub>I</sub> = –18 mA		–1.2			–1.2			V	
V <sub>OH</sub>		V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = –2 mA		V <sub>CC</sub> – 2						V	
		V <sub>CC</sub> = 4.5 V to 5.5 V, I <sub>OH</sub> = –2 mA					V <sub>CC</sub> – 2				
		V <sub>CC</sub> = 4.5 V	I <sub>OH</sub> = –3 mA	2.4	3.2		2.4	3.2			
			I <sub>OH</sub> = –12 mA	2.4							
		I <sub>OH</sub> = –15 mA					2.4				
V <sub>OL</sub>		V <sub>CC</sub> = 4.5 V		I <sub>OL</sub> = 48 mA			0.3 0.55			V	
				I <sub>OL</sub> = 64 mA			0.35 0.55				
I <sub>I</sub>	Control inputs	V <sub>CC</sub> = 5.5 V		V <sub>I</sub> = 7 V		0.1			0.1		mA
	A or B ports			V <sub>I</sub> = 5.5 V		0.1			0.1		
I <sub>IH</sub>	Control inputs	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 2.7 V		20			20			μA	
	A or B ports§			70			70				
I <sub>IL</sub>	Control inputs	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0.4 V		–0.5			–0.5			mA	
	A or B ports§			–0.75			–0.75				
I <sub>O</sub> ¶		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 2.25 V		–50 –150			–50 –150			mA	
I <sub>CC</sub>		V <sub>CC</sub> = 5.5 V		Outputs high		37 58		37 58		mA	
				Outputs low		78 123		78 123			
				Outputs disabled		51 80		51 80			

‡ All typical values are at  $V_{CC} = 5\text{ V}$ ,  $T_A = 25^\circ\text{C}$ .

§ For I/O ports, the parameters  $I_{IH}$  and  $I_{IL}$  include the off-state output current.

¶ The output conditions have been chosen to produce a current that closely approximates one half of the true short-circuit output current,  $I_{OS}$ .



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**switching characteristics (see Figure 1)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 4.5 V to 5.5 V, C <sub>L</sub> = 50 pF, R <sub>1</sub> = 500 Ω, R <sub>2</sub> = 500 Ω, T <sub>A</sub> = MIN to MAX†				UNIT
			SN54AS640		SN74AS640		
			MIN	MAX	MIN	MAX	
t <sub>PLH</sub>	A or B	B or A	1	8	2	7	ns
t <sub>PHL</sub>			1	7	2	6	
t <sub>PZH</sub>	$\overline{OE}$	A or B	2	10	2	8	ns
t <sub>PZL</sub>			2	12	2	10	
t <sub>PHZ</sub>	$\overline{OE}$	A or B	2	9	2	8	ns
t <sub>PLZ</sub>			2	16	2	13	

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

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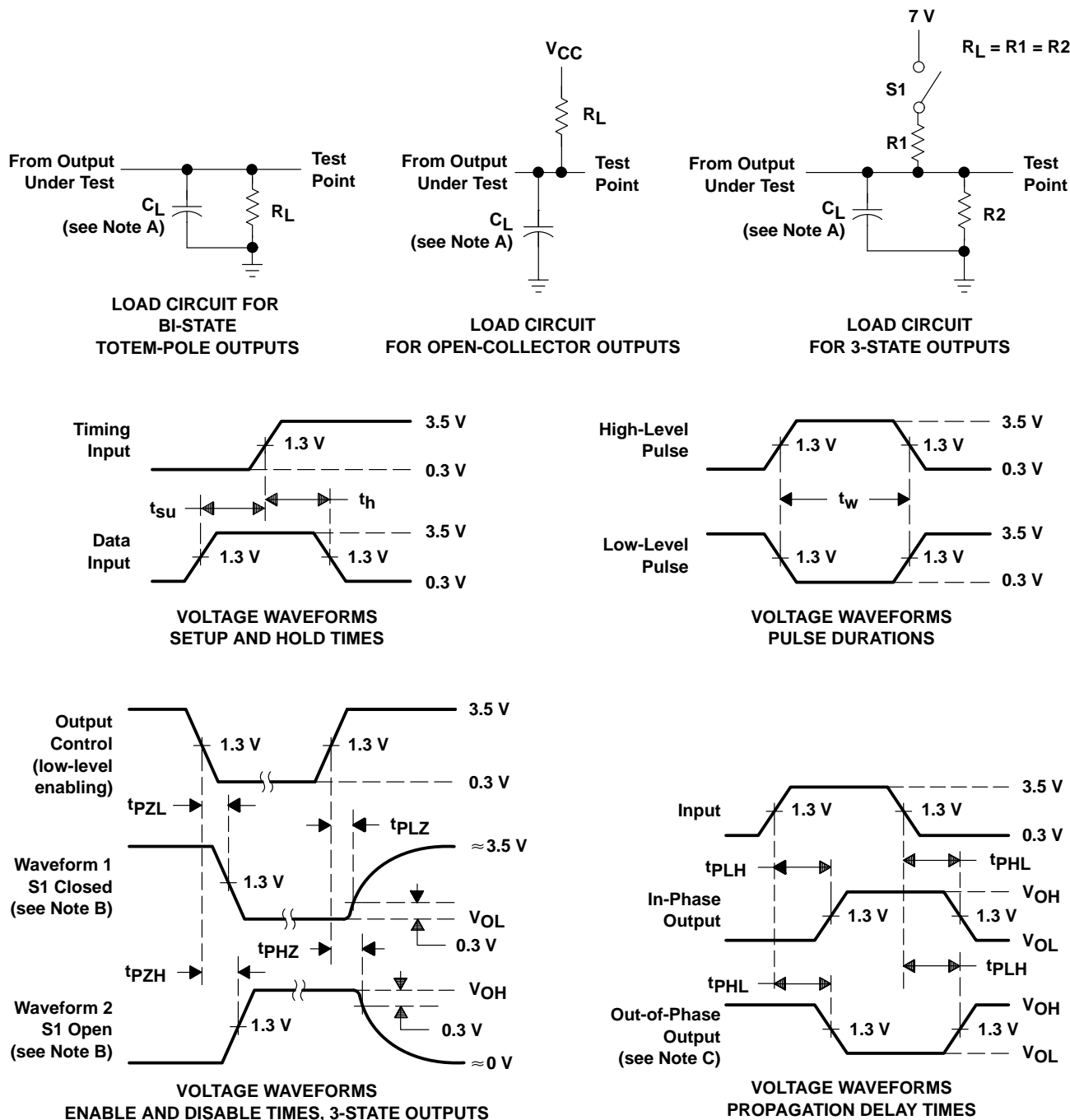
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#### PARAMETER MEASUREMENT INFORMATION

#### SERIES 54ALS/74ALS AND 54AS/74AS DEVICES



- NOTES: A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. When measuring propagation delay items of 3-state outputs, switch S1 is open.
- D. All input pulses have the following characteristics:  $PRR \leq 1$  MHz,  $t_r = t_f = 2$  ns, duty cycle = 50%.
- E. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuits and Voltage Waveforms

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